NSN 5961-01-016-5417

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-016-5417 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 reverse voltage, dc **Current Rating Per Characteristic:** 450.00 milliamperes source cutoff current absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 80009-152-0574-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0